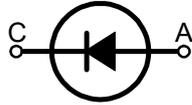


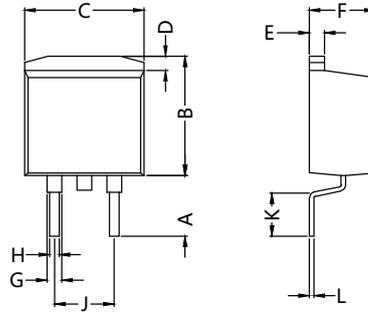
# MUR2960S

## Ultra Fast Recovery Diodes

C(TAB)



Dimensions TO-263(D<sup>2</sup>PAK)



Dim.	Millimeter		Dim.	Millimeter	
	Min.	Max.		Min.	Max.
A	9.80	10.60	D2	2.30	3.30
B	15.40	16.40	E	5.08BSC	
B1	6.00	7.40	F	14.50	16.00
B2	3.20	3.80	ØG	2.90	3.40
C	12.80	13.50	H	0.60	1.00
C1	3.20	4.00	H1	1.15	1.55
D	4.35	4.95	J	0.35	0.65
D1	2.24	2.84	K	0.00	1.60



A=Anode, NC= No connection, TAB=Cathode

	V <sub>RSM</sub> V	V <sub>RSM</sub> V
<b>MUR2960S</b>	600	600

Symbol	Test Conditions	Maximum Ratings	Unit
I <sub>FRMS</sub>	T <sub>VJ</sub> =T <sub>VJM</sub>	70	A
I <sub>FAVM</sub>	T <sub>C</sub> =85°C; rectangular, d=0.5	30	
I <sub>FRM</sub>	t <sub>p</sub> <10us; rep. rating, pulse width limited by T <sub>VJM</sub>	375	
I <sub>FSM</sub>	T <sub>VJ</sub> =45°C	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	A
	T <sub>VJ</sub> =150°C	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	
I <sup>2</sup> t	T <sub>VJ</sub> =45°C	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	A <sup>2</sup> s
	T <sub>VJ</sub> =150°C	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	
T <sub>VJ</sub> T <sub>VJM</sub> T <sub>stg</sub>		-40...+150 150 -40...+150	°C
P <sub>tot</sub>	T <sub>C</sub> =25°C	125	W
Weight	Typical	1.6	g

# MUR2960S

## Ultra Fast Recovery Diodes

Symbol	Test Conditions	Characteristic Values		Unit
		typ.	max.	
I <sub>R</sub>	T <sub>VJ</sub> =25°C; V <sub>R</sub> =V <sub>RRM</sub>		100	µA
	T <sub>VJ</sub> =25°C; V <sub>R</sub> =0.8·V <sub>RRM</sub>		50	µA
	T <sub>VJ</sub> =125°C; V <sub>R</sub> =0.8·V <sub>RRM</sub>		7	mA
V <sub>F</sub>	I <sub>F</sub> =29A; T <sub>VJ</sub> =150°C		1.4	V
	T <sub>VJ</sub> =25°C		1.6	
V <sub>TO</sub>	For power-loss calculations only		1.01	V
r <sub>T</sub>	T <sub>VJ</sub> =T <sub>VJM</sub>		7.1	mΩ
R <sub>thJC</sub>			1.0	K/W
t <sub>tr</sub>	I <sub>F</sub> =1A; -di/dt=100A/µs; V <sub>R</sub> =30V; T <sub>VJ</sub> =25°C	35	50	ns
I <sub>RM</sub>	V <sub>R</sub> =350V; I <sub>F</sub> =29A; -di <sub>F</sub> /dt=240A/µs; L≤0.05µH; T <sub>VJ</sub> =100°C	10	11	A

### FEATURES

- \* International standard package JEDEC TO-263
- \* Glass passivated chips
- \* Very short recovery time
- \* Extremely low switching losses
- \* Low I<sub>RM</sub>-values
- \* Soft recovery behaviour
- \* RoHS compliance

### APPLICATIONS

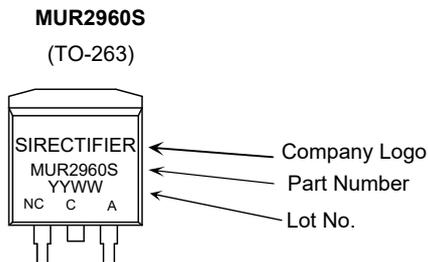
- \* Antiparallel diode for high frequency switching devices
- \* Antisaturation diode
- \* Snubber diode
- \* Free wheeling diode in converters and motor control circuits
- \* Rectifiers in switch mode power supplies (SMPS)
- \* Inductive heating and melting
- \* Uninterruptible power supplies (UPS)
- \* Ultrasonic cleaners and welders

### ADVANTAGES

- \* High reliability circuit operation
- \* Low voltage peaks for reduced protection circuits
- \* Low noise switching
- \* Low losses
- \* Operating at lower temperature or space saving by reduced cooling



### Marking



### Ordering Information

Part Number	Package	Shipping	Marking Code
MUR2960S	TO-263	50pcs / Tube or 800pcs / Tape & Reel or 1000pcs / Tape & Reel	MUR2960S

**Sirectifier®**

# MUR2960S

## Ultra Fast Recovery Diodes

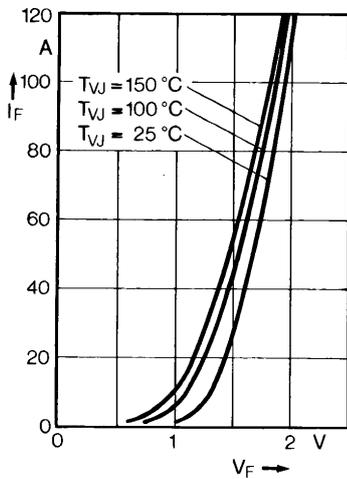


Fig. 1 Forward current versus voltage drop.

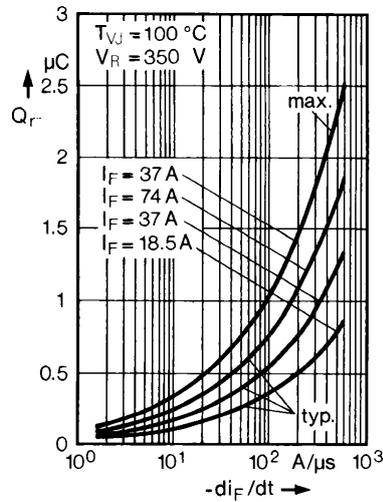


Fig. 2 Recovery charge versus  $-di_F/dt$ .

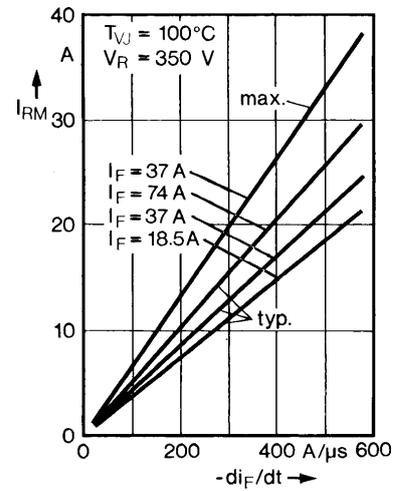


Fig. 3 Peak reverse current versus  $-di_F/dt$ .

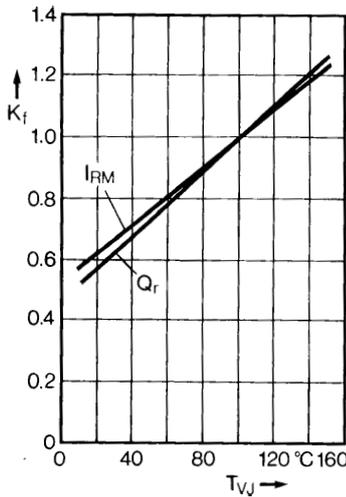


Fig. 4 Dynamic parameters versus junction temperature.

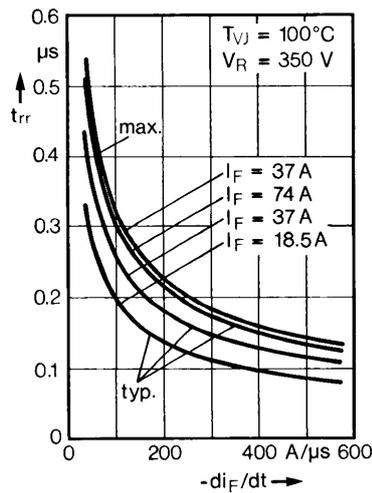


Fig. 5 Recovery time versus  $-di_F/dt$ .

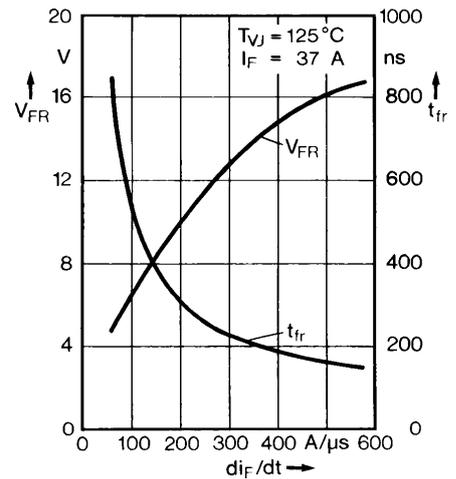


Fig. 6 Peak forward voltage versus  $di_F/dt$ .

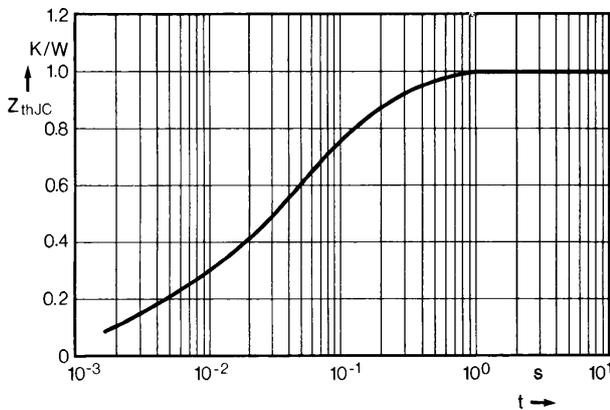


Fig. 7 Transient thermal impedance junction to case.

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